

**Reference Design using the HC55185 and the IDT821054/64 Programmable Quad PCM CODEC**

The purpose of this application note is to provide a reference design for the HC55185 and IDT821054/64 Programmable Quad PCM CODECs.

The network requirements of many countries require the analog subscriber line circuit (SLIC) to terminate the subscriber line with an impedance for voiceband frequencies which is complex, rather than resistive (e.g. 600Ω). The HC55185 accomplishes this impedance matching with a single network connected between the VTX pin and the -IN pin.

The IDT821054/64 Quad PCM CODECs uses an intergrated programmable DSP to realize AC Impedance Matching, Transhybrid Balance, Frequency Response Correction and Gain Setting functions.

Discussed in this application note are the following:

- 2-wire impedance matching.
- Receive gain (4-wire to 2-wire) and transmit gain (2-wire to 4-wire) calculations.
- Reference design for both 600Ω and 200Ω +680Ω||0.1μF (China Complex Impedance).

**Impedance Matching**

Impedance matching of the HC55185 to the subscriber load is important for optimization of 2 wire return loss, which in turn cuts down on echoes in the end to end voice communication path. Impedance matching of the HC55185 is accomplished by making the SLIC's impedance (Z<sub>O</sub>, Figure 1) equal to the desired terminating impedance Z<sub>L</sub>, minus the value of the protection resistors (R<sub>P</sub>).

With the HC55185 programmed to match a Z<sub>L</sub> of 600Ω, the IDT821054/64 uses an integrated programmable DSP to realize any AC impedance. The formula to program the HC55185 to match a 2-wire impedance of 600Ω is shown in Equation 1.

$$R_S = 133.3 \cdot (Z_L - 2R_P) = 133.3 \cdot (600\Omega - 2R_P) \quad \text{(EQ. 1)}$$

The value of R<sub>S</sub> with 49Ω protection resistors is 66.9kΩ. The closest standard value is 66.5kΩ.

**SLIC in the Active Mode**

Figure 2 shows a simplified AC transmission model of the HC55185 and the connection of the IDT821054/64 to the SLIC. Circuit analysis of the HC55185 yields the following design equations:

The Sense Amplifier is configured as a 4 input differential amplifier with a gain of 3/4. The voltage at the output of the sense amplifier (V<sub>SA</sub>) is calculated using superposition. V<sub>SA1</sub> is the voltage resulting from V<sub>1</sub>, V<sub>SA2</sub> is the voltage resulting from V<sub>2</sub> and so on (reference Figure 2).

$$V_{SA1} = -\frac{3}{4}(V_1) \quad \text{(EQ. 2)}$$

$$V_{SA2} = \frac{3}{4}(V_2) \quad \text{(EQ. 3)}$$

$$V_{SA3} = -\frac{3}{4}(V_3) \quad \text{(EQ. 4)}$$

$$V_{SA4} = \frac{3}{4}(V_4) \quad \text{(EQ. 5)}$$

$$V_{SA} = [(V_2 - V_1) + (V_4 - V_3)]\frac{3}{4} = [\Delta V + \Delta V]\frac{3}{4} \quad \text{(EQ. 6)}$$

Where ΔV is equal to I<sub>M</sub>R<sub>SENSE</sub> (R<sub>SENSE</sub> = 20Ω)

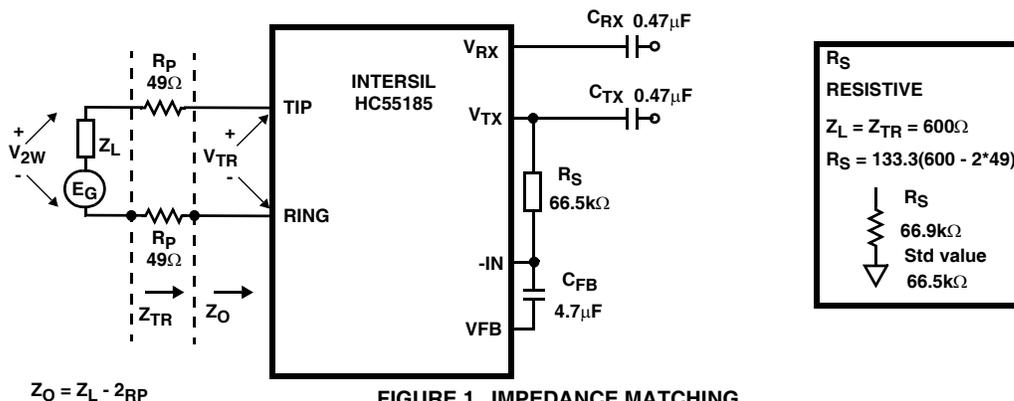
$$V_{SA} = 2(\Delta I_M \times 20)\frac{3}{4} = \Delta I_M 30 \quad \text{(EQ. 7)}$$

The voltage at VTX is equal to:

$$V_{TX} = -V_{SA}\left(\frac{R_S}{8K}\right) = -\left(\frac{R_S}{8K}\right)\Delta I_M 30 \quad \text{(EQ. 8)}$$

V<sub>TR</sub> is defined in Figure 2, note polarity assigned to V<sub>TR</sub>:

$$V_{TR} = 2(V_{RX} + V_{TX}) \quad \text{(EQ. 9)}$$



Setting  $V_{RX}$  equal to zero, substituting EQ. 8 into EQ. 9 and defining  $Z_O = -V_{TR}/\Delta I_M$  will enable the user to determine the require feedback to match the line impedance at  $V_{2W}$ .

$$Z_O = \frac{1}{133.33} R_S \quad (\text{EQ. 10})$$

$Z_O$  is the source impedance of the device and is defined as  $Z_O = Z_L - 2R_P$ .  $Z_L$  is the line impedance.  $R_S$  is defined as:

$$R_S = 133.33(Z_L - 2R_P) \quad (\text{EQ. 11})$$

Node Equation at HC55185  $V_{RX}$  input

$$I_X = \frac{V_{RX}}{R} + \frac{V_{TX}}{R} \quad (\text{EQ. 12})$$

Substitute Equation 8 into Equation 12

$$I_X = \frac{V_{RX}}{R} - \left( \frac{R_S \Delta I_M 30}{8K} \right) \quad (\text{EQ. 13})$$

Loop Equation at HC55185 feed amplifiers and load

$$I_X R - V_{TR} + I_X R = 0 \quad (\text{EQ. 14})$$

Substitute Equation 13 into Equation 14

$$V_{TR} = 2V_{RX} - \left( \frac{R_S \Delta I_M 60}{8K} \right) \quad (\text{EQ. 15})$$

Substitute Equation 10 for  $R_S$  and  $-V_{2W}/Z_L$  for  $\Delta I_M$  into Equation 15.

$$V_{TR} = 2V_{RX} + \frac{Z_O V_{2W}}{Z_L} \quad (\text{EQ. 16})$$

Loop Equation at Tip/Ring interface

$$V_{2W} - I_M 2R_P + V_{TR} = 0 \quad (\text{EQ. 17})$$

Substitute Equation 16 into Equation 17 and combine terms

$$V_{2W} \left[ \frac{Z_L + Z_O + 2R_P}{Z_L} \right] = -2V_{RX} \quad (\text{EQ. 18})$$

where:

$V_{RX}$  = The input voltage at the  $V_{RX}$  pin.

$V_{SA}$  = An internal node voltage that is a function of the loop current and the output of the Sense Amplifier.

$I_X$  = Internal current in the SLIC that is the difference between the input receive current and the feedback current.

$I_M$  = The AC metallic current.

$R_P$  = A protection resistor (typical 49.9 $\Omega$ ).

$R_S$  = An external resistor/network for matching the line impedance.

$V_{TR}$  = The tip to ring voltage at the output pins of the SLIC.

$V_{2W}$  = The tip to ring voltage including the voltage across the protection resistors.

$Z_L$  = The line impedance.

$Z_O$  = The source impedance of the device.

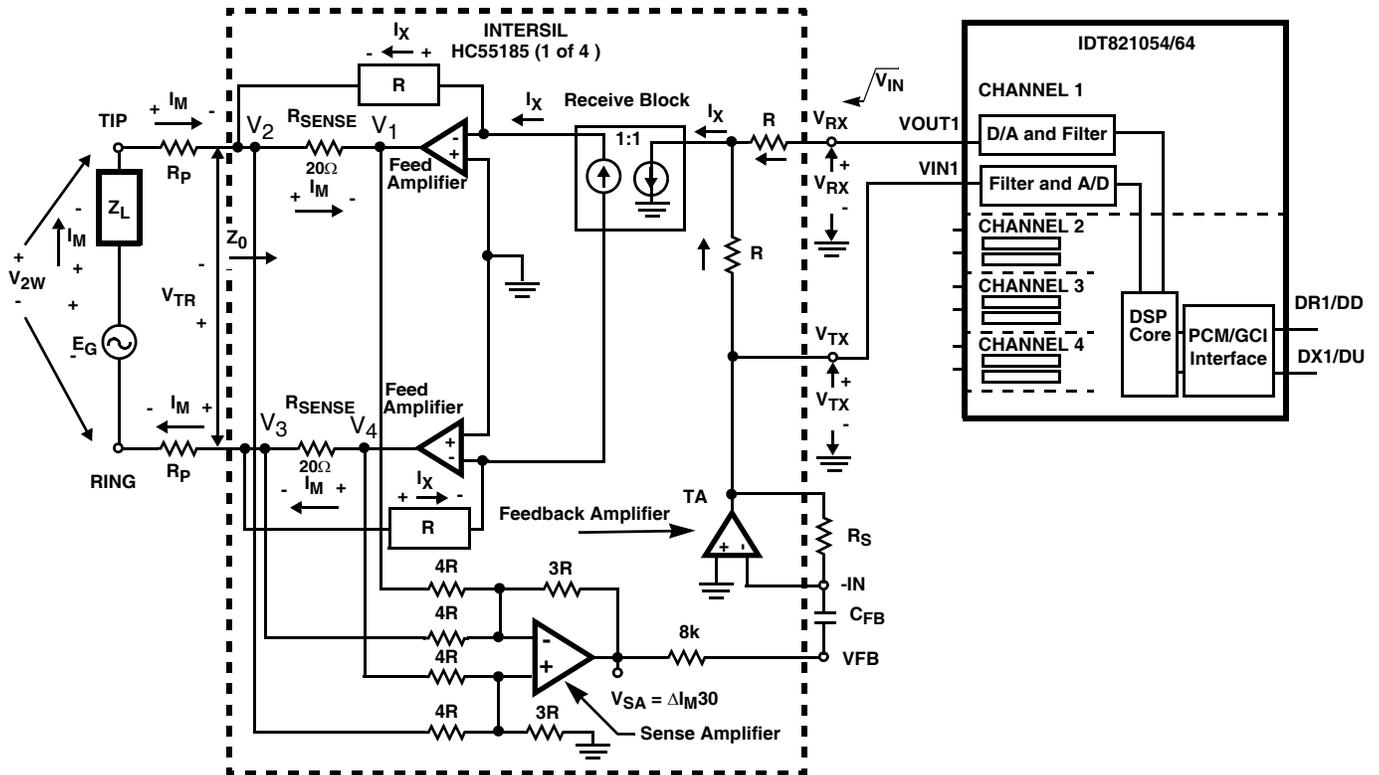


FIGURE 2. HC55185 SIMPLIFIED AC TRANSMISSION CIRCUIT AND IDT821054/64

## HC55185 Receive Gain ( $V_{RX}$ to $V_{2W}$ )

4-wire to 2-wire gain across the HC55185 is equal to the  $V_{2W}$  divided by the input voltage  $V_{RX}$ , reference Figure 2. The receive gain is calculated using Equation 18.

Equation 19 expresses the receive gain ( $V_{RX}$  to  $V_{2W}$ ) in terms of network impedances. From Equation 11, the value of  $R_S$  was set to match the line impedance ( $Z_L$ ) to the HC55185 plus the protection resistors ( $Z_O + 2R_P$ ). This results in a 4-wire to 2-wire gain of -1, as shown in EQ19.

$$G_{4-2} = \frac{V_{2W}}{V_{RX}} = -2 \frac{Z_L}{Z_L + Z_O + 2R_P} = -2 \frac{Z_L}{Z_L + Z_L} = -1 \quad (\text{EQ. 19})$$

## Receive Gain Across the System

The receive gain across the system is defined as the gain from the PCM highway to the phone ( $V_{2W}$ ). With the receive gain through the HC55185 set to 1, the receive gain across the system is entirely controlled by programming the IDT821054/64. The IDT821054/64 can program the receive gain across the system in two ways (reference Figure 3).

- The first is by programming the signal gain in its analog form. The analog receive gain, also known as Digital to Analog (D/A) gain, can be programmed in the IDT821054/64 to be either 0dB or -6dB.
- The second is by programming the signal gain (via coefficients) when its in digital form. The digital form of the receive path can be programmed from +3 to -12dB with minimum 0.1dB steps.

This results in a possible receive gain (D/A) programming range from +3dB to -18dB. **Note: Analog gain brings less noise than digital gain. When allocating the CODEC gain, the majority of the required gain should be preformed in the analog stage.**

Reference section titled "Information Required for IDT to Calculate IDT821054/64 CODEC DSP Coefficients" for information on obtaining coefficients for your design.

## Transmit Gain Across HC55185 ( $E_G$ to $V_{TX}$ )

The 2-wire to 4-wire gain is equal to  $V_{TX}/E_G$  with  $V_{RX} = 0$ , reference Figure 2.

$$\text{Loop Equation} \quad -E_G + Z_L I_M + 2R_P I_M - V_{TR} = 0 \quad (\text{EQ. 20})$$

From Equation 16 with  $V_{RX} = 0$

$$V_{TR} = \frac{Z_O V_{2W}}{Z_L} \quad (\text{EQ. 21})$$

Substituting Equation 21 into Equation 20 and simplifying.

$$E_G = -V_{2W} \left[ \frac{Z_L + 2R_P + Z_O}{Z_L} \right] \quad (\text{EQ. 22})$$

Substituting Equation 10 into Equation 8 and defining  $\Delta I_M = -V_{2W}/Z_L$  results in Equation 23 for  $V_{TX}$ .

$$V_{TX} = \frac{V_{2W}}{2} \left[ \frac{Z_L - 2R_P}{Z_L} \right] \quad (\text{EQ. 23})$$

Combining Equations 22 and 23 results in Equation 24.

$$G_{2-4} = \frac{V_{TX}}{E_G} = -\frac{Z_L - 2R_P}{2(Z_L + 2R_P + Z_O)} = -\frac{Z_O}{2(Z_L + 2R_P + Z_O)} \quad (\text{EQ. 24})$$

A more useful form of the equation is rewritten in terms of  $V_{TX}/V_{2W}$ . A voltage divider equation is written to convert from  $E_G$  to  $V_{2W}$  as shown in Equation 25.

$$V_{2W} = \left( \frac{Z_O + 2R_P}{Z_L + Z_O + 2R_P} \right) E_G \quad (\text{EQ. 25})$$

Substituting  $Z_L = Z_O + 2R_P$  and rearranging Equation 25 in terms of  $E_G$  results in Equation 26.

$$E_G = 2V_{2W} \quad (\text{EQ. 26})$$

Substituting Equation 26 into Equation 24 results in an equation for 2-wire to 4-wire gain that's a function of the synthesized input impedance of the SLIC and the protection resistors.

$$G_{2-4} = \frac{V_{TX}}{V_{2W}} = \frac{Z_O}{(Z_L + 2R_P + Z_O)} = 0.416 \quad (\text{EQ. 27})$$

$Z_L$  is set to 600Ω,  $Z_O$  is programmed with  $R_S$  to be 498.76Ω (66.5kΩ/133.33), and  $R_P$  is equal to 49.9Ω. This results in a 2-wire to 4-wire gain of 0.416 or -7.6dB.

## Transmit Gain Across the System

The transmit gain across the system is defined as the gain from the phone or 2-wire side ( $V_{2W}$ ) to the PCM highway. Setting the gain of the IDT821054/64 will have to account for the attenuated signal through the HC55185. The system gain is entirely controlled by programming the IDT821054/64. The IDT821054/64 can program the transmit gain across the system in two ways (reference Figure 3).

- The first is by programming the signal gain in its analog form. The analog transmit gain, also known as Analog to Digital (A/D) gain, can be programmed in the IDT821054/64 to be either 0dB or +6dB.
- The second is by programming the signal gain (via coefficients) when its in digital form. The digital form of the transmit path can be programmed from -3dB to +12dB with minimum 0.1dB steps.

This results in a possible transmit gain (A/D) programming range from -3dB to +18dB. **Note: Analog gain brings less noise than digital gain. When allocating the CODEC gain, the majority of the required gain should be preformed in the analog stage.**

Reference section titled "Information Required for IDT to Calculate IDT821054/64 CODEC DSP Coefficients" for information on obtaining coefficients for your design.

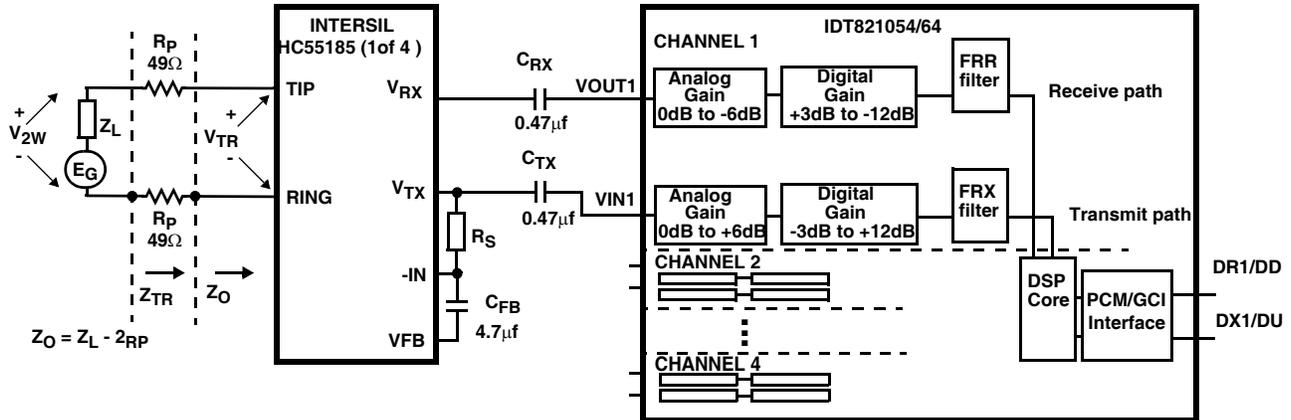


FIGURE 3. RECEIVE GAIN G(4-2), TRANSMIT GAIN (2-4)

### Transhybrid Balance G(4-4)

Transhybrid balance is a measure of how well the input signal is canceled (that being received by the SLIC) from the transmit signal (that being transmitted from the SLIC to the CODEC). Without this function, voice communication would be difficult because of the echo. The Transhybrid balancing filter inside the IDT821054/64 is used to adjust transhybrid balance to ensure the echo cancellation meets the ITU-T specifications. The coefficient for Echo Cancellation is ECF.

### Frequency Response Correction

The FRR filter in the receive path and the FRX filter in the transmit path can be programmed to correct any frequency distortion caused by the impedance matching filters. The coefficients of Frequency Response Correction are FRR for receive path and FRX for the transmit path.

### Information Required for IDT to Calculate IDT821054/64 CODEC DSP Coefficients

For IDT to calculate IDT821054/64 DSP coefficient, customers should provide the following information about their subscriber line card:

- Accurate SLIC PSPICE model. It can be provided in .lib file or PSPICE schematic file.
- System Impedance
- Gain (Transmit path and Receive path)

Using the DSP coefficients provided by IDT, the overall performance of the system will pass ITU-T requirements.

When the COF RAM button is selected from the MPI Operation General Interface screen, the COF RAM Operation screen will appear (Figure 4). From this screen, the user can configure all the coefficients for the current channel.

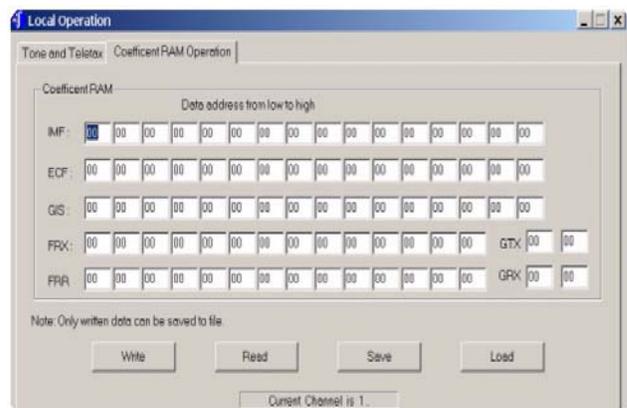


FIGURE 4. COEFFICIENT RAM OPERATION SCREEN

### Reference Design of the HC55185 and the IDT821054/64 With a 600Ω Load

The design criteria is as follows:

- 4-wire to 2-wire gain (DR1/DD to  $V_{2W}$ ) equal 0dB
- 2-wire to 4-wire gain ( $V_{2W}$  to DX1/DU) equal 0dB
- $R_p = 49.9\Omega$

Figure 5 gives the reference design using the Intersil HC55185 and the IDT821054/64 Programmable Quad PCM CODEC. Also shown in Figure 5 are the voltage levels at specific points in the circuit.

### Impedance Matching

The 2-wire impedance is matched to the line impedance  $Z_0$  using Equation 1, repeated here in Equation 28.

$$R_S = 133.3 \cdot (Z_L - 2R_P) \quad (\text{EQ. 28})$$

For a line impedance of 600Ω,  $R_S$  equals:

$$R_S = 133.3 \cdot (600 - 98) = 66.9k\Omega \quad (\text{EQ. 29})$$

The closest standard value for  $R_S$  would be 66.5kΩ.

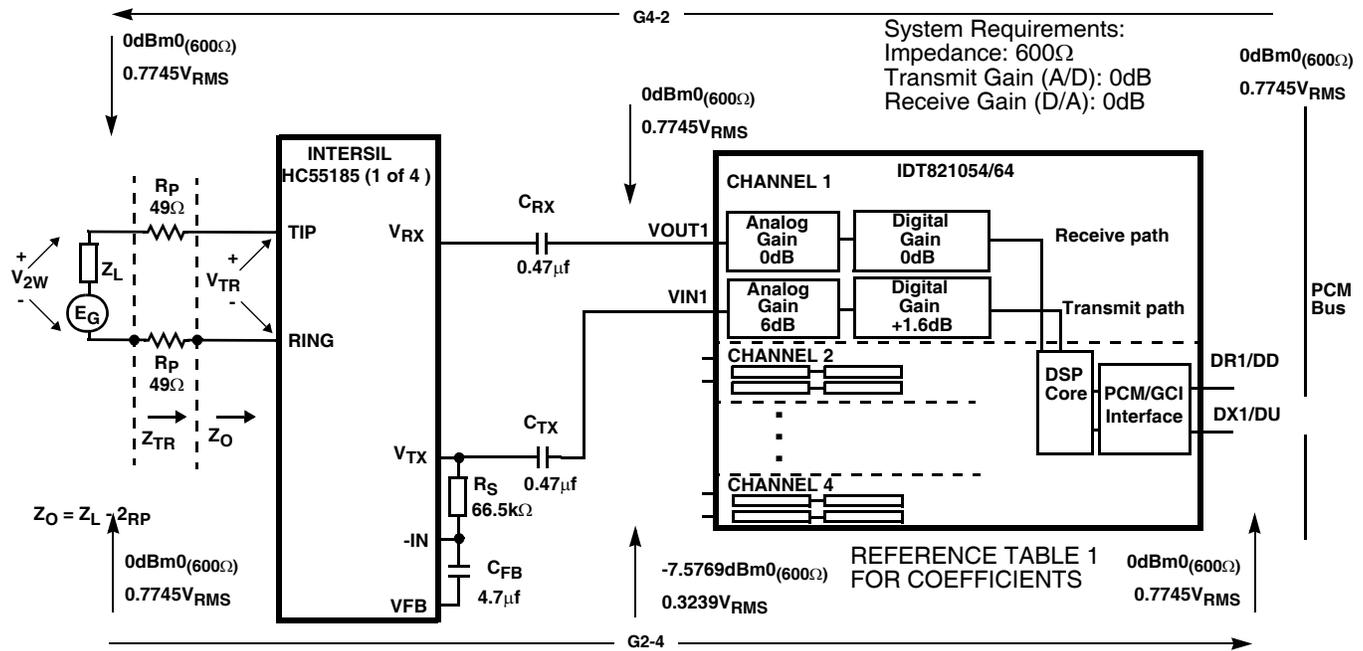


FIGURE 5. REFERENCE DESIGN OF THE HC55185 AND THE IDT821054/64 WITH A 600Ω LOAD IMPEDANCE

However, it would be very convenient and cost effective if system manufacturers can use only one type of line card to meet different impedance requirements and different gain requirements. The programmability of IDT821054/64 can help system manufactures to reach this goal. By using different coefficients this reference design can meet both 600Ω and 200Ω + 680Ω||0.1μ F impedance requirements.

With the value of  $R_S$  selected to be 66.5kΩ ± 1%, the coefficients (with a line impedance of 600Ω) are given in Table 1.

### Specific Implementation for China

The design criteria for a China specific solution are as follows:

- Desired line circuit impedance is 200 + 680//0.1μF
- Receive gain ( $V_{2W}/(DR1/DD)$ ) is -3.5dB
- Transmit gain ( $(DX1/DU)/V_{2W}$ ) is 0dB
- 0dBm0 is defined as 1mW into the complex impedance at 1020Hz
- $R_p = 49.9\Omega$

Figure 6 gives the reference design using the Intersil HC55185 and the IDT821054/64 Programmable Quad PCM CODEC. Also shown in Figure 6 are the voltage levels at specific points in the circuit. Note: The transmit gain of the system is 0dB (-2.19dB<sub>(811Ω)</sub> = -3.5dB<sub>(600Ω)</sub>) as explained in the following section.

### Adjustment to Get -3.5dBm0 at the Load Referenced to 600Ω

The voltage equivalent to 0dBm0 into 811Ω (0dBm0<sub>(811Ω)</sub>) is calculated using Equation 30 (811Ω is the impedance of complex China load at 1020Hz).

$$0dBm_{(811\Omega)} = 10\log \frac{V^2}{811(0.001)} = 0.90055V_{RMS} \quad (EQ. 30)$$

The gain referenced back to 0dBm0<sub>(600Ω)</sub> is equal to:

$$GAIN = 20\log \frac{0.90055V_{RMS}}{0.7745V_{RMS}} = 1.309dB \quad (EQ. 31)$$

The adjustment to get -3.5dBm0 at the load referenced to 600Ω is:

$$Adjustment = -3.5dBm0 + 1.309dB = -2.19dB \quad (EQ. 32)$$

The voltage at the load (referenced to 600Ω) is given in Equation 33:

$$-2.19dBm_{(600\Omega)} = 10\log \frac{V^2}{600(0.001)} = 0.60196V_{RMS} \quad (EQ. 33)$$

### Impedance Matching

With the value of  $R_S$  selected to be 66.5kΩ ± 1%, the coefficients (with a line impedance of 200Ω + 680Ω||0.1μ F) are given in Table 2.

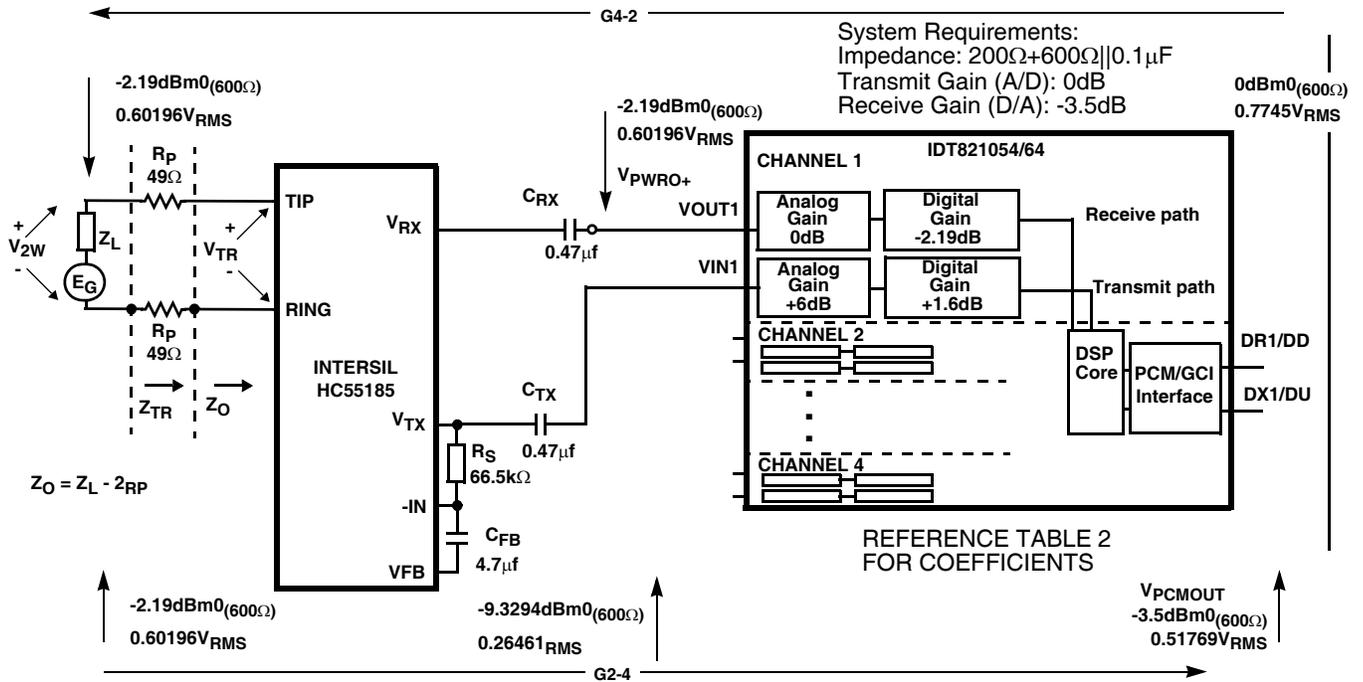


FIGURE 6. REFERENCE DESIGN OF THE HC55185 AND THE IDT821054/64 WITH CHINA COMPLEX LOAD IMPEDANCE

TABLE 1. 600Ω COEFFICIENTS, SYSTEM GAINS: (TRANSMIT GAIN (0dB), RECEIVE GAIN (0dB)),  
CODEC ANALOG GAINS: (TRANSMIT PATH +6dB, RECEIVE PATH 0dB)

Coefficient RAM				CHANNEL 1													
IMF:	47	08	53	F5	00	00	00	00	00	00	00	00	00	00	00	00	00
ECF:	3C	03	00	00	00	00	00	00	00	00	56	62	F4	D6	00	00	
KM:	00	00	34	E6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	36	02	97	DE	95	48	95	48	97	DE	36	02	99	31	<b>GTX</b>	FF	1F
ACR:	F8	00	55	FD	70	3F	70	3F	55	FD	F8	00	CE	84	<b>GRX</b>	0C	03
Coefficient RAM				CHANNEL 2													
IMF:	47	08	53	F5	00	00	00	00	00	00	00	00	00	00	00	00	
ECF:	3C	03	00	00	00	00	00	00	00	00	56	62	F4	D6	00	00	
KM:	00	00	34	E6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	36	02	97	DE	95	48	95	48	97	DE	36	02	99	31	<b>GTX</b>	FF	1F
ACR:	F8	00	55	FD	70	3F	70	3F	55	FD	F8	00	CE	84	<b>GRX</b>	0C	03
Coefficient RAM				CHANNEL 3													
IMF:	47	08	53	F5	00	00	00	00	00	00	00	00	00	00	00	00	
ECF:	3C	03	00	00	00	00	00	00	00	00	56	62	F4	D6	00	00	
KM:	00	00	34	E6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	36	02	97	DE	95	48	95	48	97	DE	36	02	99	31	<b>GTX</b>	FF	1F
ACR:	F8	00	55	FD	70	3F	70	3F	55	FD	F8	00	CE	84	<b>GRX</b>	0C	03

TABLE 1. 600Ω COEFFICIENTS, SYSTEM GAINS: (TRANSMIT GAIN (0dB), RECEIVE GAIN (0dB)),  
CODEC ANALOG GAINS: (TRANSMIT PATH +6dB, RECEIVE PATH 0dB) (Continued)

Coefficient RAM				CHANNEL 4													
IMF:	47	08	53	F5	00	00	00	00	00	00	00	00	00	00	00	00	
ECF:	3C	03	00	00	00	00	00	00	00	00	56	62	F4	D6	00	00	
KM:	00	00	34	E6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	36	02	97	DE	95	48	95	48	97	DE	36	02	99	31	<b>GTX</b>	FF	1F
ACR:	F8	00	55	FD	70	3F	70	3F	55	FD	F8	00	CE	84	<b>GRX</b>	0C	03

TABLE 2. 200Ω + 680Ω || 0.1μF COEFFICIENTS, SYSTEM GAINS: (TRANSMIT GAIN (0dB), RECEIVE GAIN (-3.5dB)),  
CODEC ANALOG GAINS: (TRANSMIT PATH +6dB, RECEIVE PATH 0dB)

COEFFICIENT RAM				CHANNEL 1													
IMF:	52	F8	20	1D	00	00	00	00	22	65	00	00	00	00	00	00	
ECF:	0B	03	00	00	00	00	00	00	00	00	36	72	29	C2	00	00	
KM:	00	00	74	C6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	C9	FE	9C	10	D4	45	D4	45	9C	10	C9	FE	00	38	<b>GTX</b>	FF	1F
ACR:	0A	FA	1D	0D	AF	39	AF	39	1D	0D	0A	FA	CE	84	<b>GRX</b>	0C	03
COEFFICIENT RAM				CHANNEL 2													
IMF:	52	F8	20	1D	00	00	00	00	22	65	00	00	00	00	00	00	
ECF:	0B	03	00	00	00	00	00	00	00	00	36	72	29	C2	00	00	
KM:	00	00	74	C6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	C9	FE	9C	10	D4	45	D4	45	9C	10	C9	FE	00	38	<b>GTX</b>	FF	1F
ACR:	0A	FA	1D	0D	AF	39	AF	39	1D	0D	0A	FA	CE	84	<b>GRX</b>	0C	03
COEFFICIENT RAM				CHANNEL 3													
IMF:	52	F8	20	1D	00	00	00	00	22	65	00	00	00	00	00	00	
ECF:	0B	03	00	00	00	00	00	00	00	00	36	72	29	C2	00	00	
KM:	00	00	74	C6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	C9	FE	9C	10	D4	45	D4	45	9C	10	C9	FE	00	38	<b>GTX</b>	FF	1F
ACR:	0A	FA	1D	0D	AF	39	AF	39	1D	0D	0A	FA	CE	84	<b>GRX</b>	0C	03
COEFFICIENT RAM				CHANNEL 4													
IMF:	52	F8	20	1D	00	00	00	00	22	65	00	00	00	00	00	00	
ECF:	0B	03	00	00	00	00	00	00	00	00	36	72	29	C2	00	00	
KM:	00	00	74	C6	00	00	00	00	00	00	00	00	00	00	00	00	
ACT:	C9	FE	9C	10	D4	45	D4	45	9C	10	C9	FE	00	38	<b>GTX</b>	FF	1F
ACR:	0A	FA	1D	0D	AF	39	AF	39	1D	0D	0A	FA	CE	84	<b>GRX</b>	0C	03

## Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.  
"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.  
"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.  
Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.  
(Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.  
(Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)



### SALES OFFICES

Renesas Electronics Corporation

<http://www.renesas.com>

Refer to "<http://www.renesas.com/>" for the latest and detailed information.

**Renesas Electronics America Inc.**  
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.  
Tel: +1-408-432-8888, Fax: +1-408-434-5351

**Renesas Electronics Canada Limited**  
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3  
Tel: +1-905-237-2004

**Renesas Electronics Europe Limited**  
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K  
Tel: +44-1628-651-700, Fax: +44-1628-651-804

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**  
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852-2886-9022

**Renesas Electronics Taiwan Co., Ltd.**  
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

**Renesas Electronics Singapore Pte. Ltd.**  
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

**Renesas Electronics Malaysia Sdn.Bhd.**  
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

**Renesas Electronics India Pvt. Ltd.**  
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India  
Tel: +91-80-67208700, Fax: +91-80-67208777

**Renesas Electronics Korea Co., Ltd.**  
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5338